

PJQ5542V-AU

40V N-Channel Enhancement Mode MOSFET

Voltage	40 V	Current	136 A
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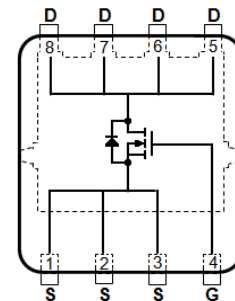
Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@20A<3m\Omega$
- $R_{DS(ON)}$, $V_{GS}@7V$, $I_D@20A<3.6m\Omega$
- Excellent FOM
- Standard Level Drive
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN5060-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.08 grams

DFN5060-8L



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	40	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current ^(Note 3)	$T_C=25^{\circ}C$	I_D	136	A
	$T_C=100^{\circ}C$		96	
Pulsed Drain Current ^(Note 1)	$T_C=25^{\circ}C$	I_{DM}	544	
Power Dissipation	$T_C=25^{\circ}C$	P_D	100	W
	$T_C=100^{\circ}C$		50	
Continuous Drain Current ^(Note 4)	$T_A=25^{\circ}C$	I_D	24.8	A
	$T_A=70^{\circ}C$		20.8	
Power Dissipation	$T_A=25^{\circ}C$	P_D	3.3	W
	$T_A=70^{\circ}C$		2.3	
Single Pulse Avalanche Energy ^(Note 5)		E_{AS}	240	mJ
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~175	$^{\circ}C$
Thermal Resistance ^(Note 4)	Junction to Case	$R_{\theta JC}$	1.5	$^{\circ}C/W$
	Junction to Ambient	$R_{\theta JA}$	45	



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Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	40	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =50uA	2	2.8	3.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A	-	2.4	3	mΩ
		V _{GS} =7V, I _D =20A	-	2.8	3.6	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =40V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
Dynamic ^(Note 6)						
Total Gate Charge	Q _g	V _{DS} =32V, I _D =20A, V _{GS} =10V	-	43	-	nC
Gate-Source Charge	Q _{gs}		-	13	-	
Gate-Drain Charge	Q _{gd}		-	11	-	
Input Capacitance	C _{iss}	V _{DS} =25V, V _{GS} =0V, f=1MHz	-	3050	-	pF
Output Capacitance	C _{oss}		-	580	-	
Reverse Transfer Capacitance	C _{rss}		-	77	-	
Gate resistance	R _g	f=1MHz	-	0.8	-	Ω
Turn-On Delay Time	td _(on)	V _{DS} =32V, I _D =20A, V _{GS} =10V, R _G =3Ω (Note 2)	-	23	-	ns
Turn-On Rise Time	tr		-	5	-	
Turn-Off Delay Time	td _(off)		-	37	-	
Turn-Off Fall Time	tf		-	9	-	
Drain-Source Diode						
Diode Forward Current	I _S	T _C =25 ⁰ C	-	-	136	A
Pulsed Diode Forward Current	I _{SM}		-	-	544	
Diode Forward Voltage	V _{SD}	I _S =20A, V _{GS} =0V	-	0.8	1.3	V
Reverse Recovery Time	T _{rr}	V _{GS} =0V, I _S =20A	-	41	-	ns
Reverse Recovery Charge	Q _{rr}	dI _S /dt=100A/us	-	37	-	nC

NOTES :

1. Pulse width $\leq 100\mu s$, Duty cycle $\leq 2\%$.
2. Essentially independent of operating temperature typical characteristics.
3. Chip capability with an $R_{\theta JC}=1.5^{\circ}\text{C/W}$, Package limited 100A.
4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz. square pad of copper.
5. The test condition is $L=0.5mH$, $I_{AS}=31A$, $V_{DD}=30V$, $V_{GS}=10V$, Starting $T_J=25^{\circ}\text{C}$.
6. Guaranteed by design, not subject to production testing.

PJQ5542V-AU

TYPICAL CHARACTERISTIC CURVES

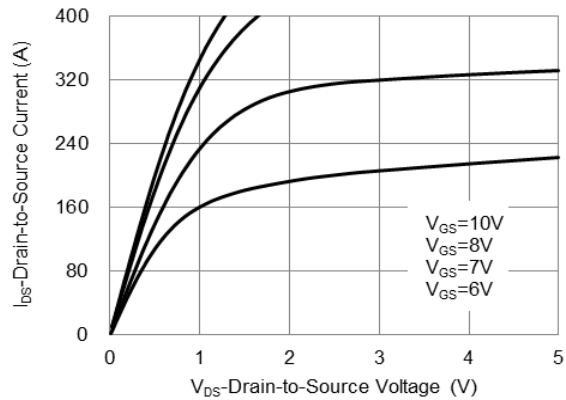


Fig.1 On-Region Characteristics

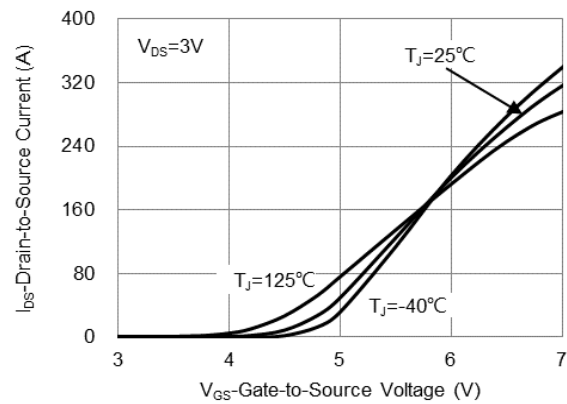


Fig.2 Transfer Characteristics

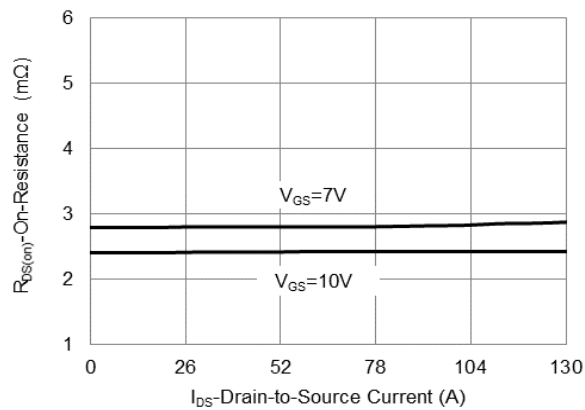


Fig.3 On-Resistance vs. Drain Current

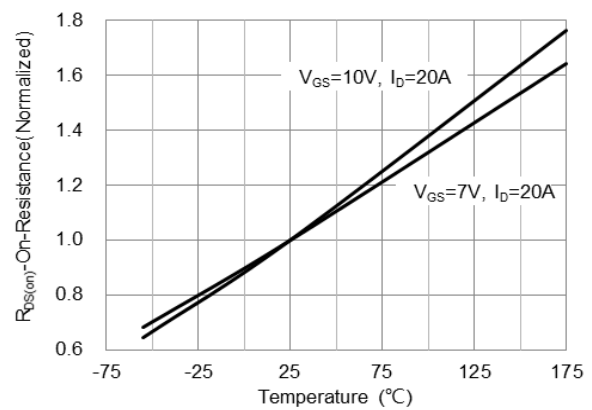


Fig.4 On-Resistance vs. Junction temperature

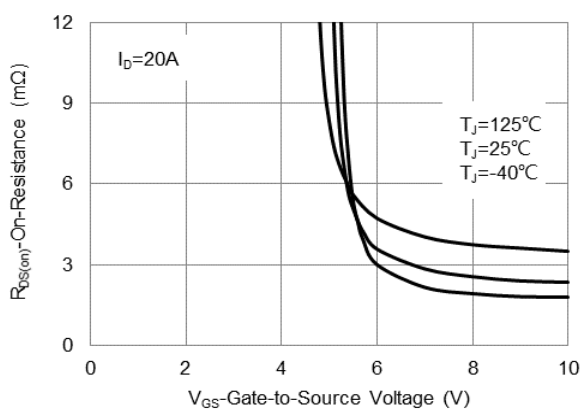


Fig.5 On-Resistance Variation with V_{GS}

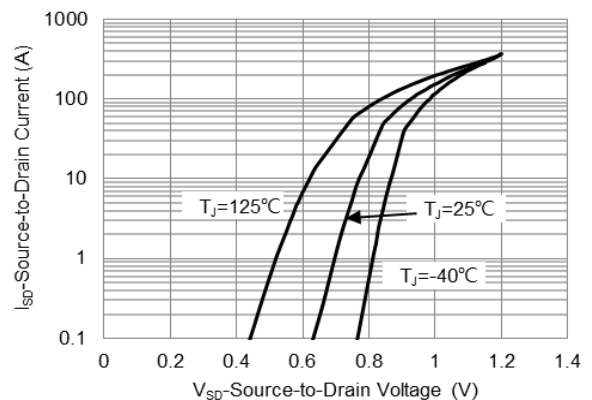
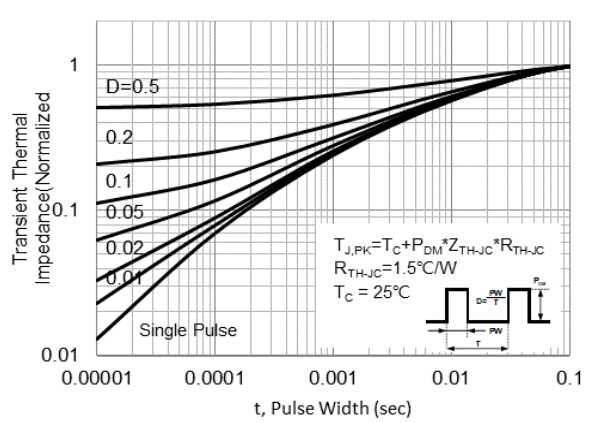
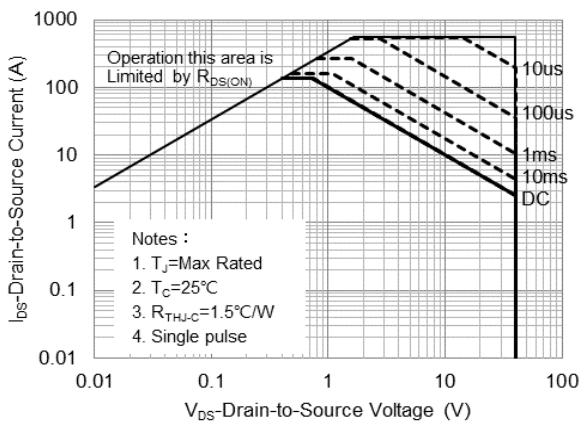
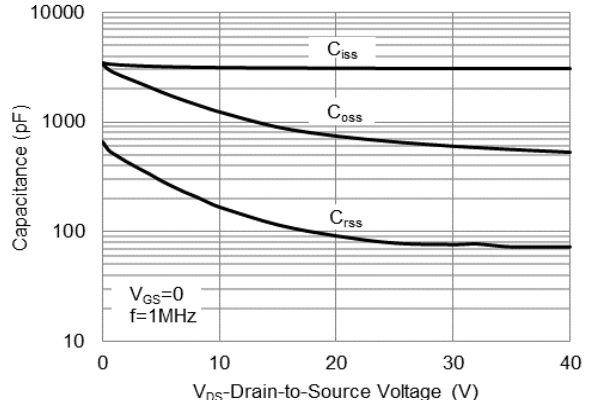
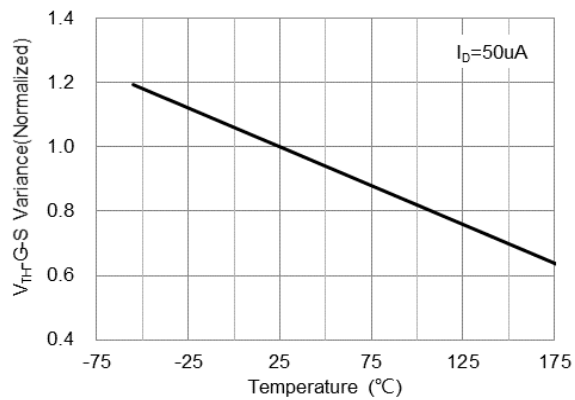
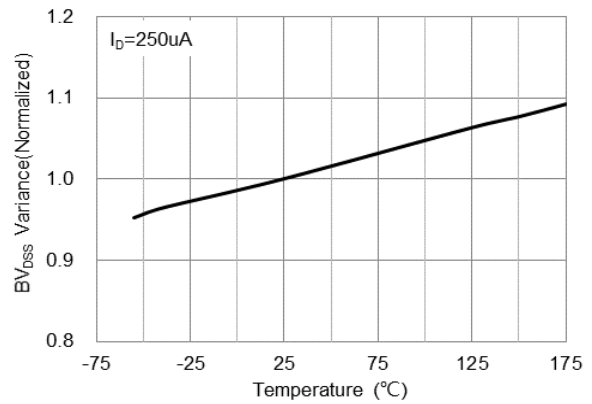
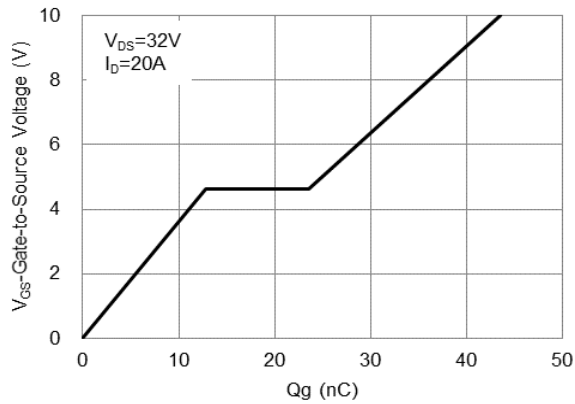


Fig.6 Source-Drain Diode Forward Voltage

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TYPICAL CHARACTERISTIC CURVES



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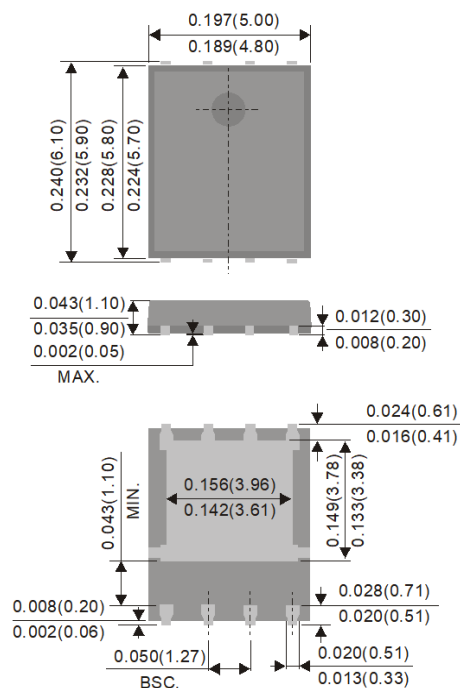
Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJQ5542V-AU	DFN5060-8L	3K pcs / 13" reel	Q5542V

Packaging Information & Mounting Pad Layout

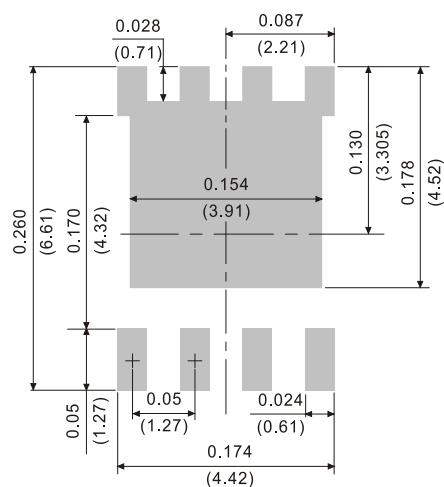
DFN5060-8L Dimension

Unit: inch(mm)



DFN5060-8L Pad Layout

Unit: inch(mm)





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